

# LMR62421 SIMPLE SWITCHER® 24V<sub>OUT</sub>, 2.1A Step-Up Voltage Regulator in SOT-23

Check for Samples: [LMR62421](#)

## FEATURES

- Input Voltage Range of 2.7V to 5.5V
- Output Voltage up to 24V
- Switch Current up to 2.1A
- 1.6 MHz Switching Frequency
- Low Shutdown I<sub>q</sub>, 80 nA
- Cycle-by-Cycle Current Limiting
- Internally Compensated
- Internal Soft-Start
- 5-Pin SOT-23 (2.92 x 2.84 x 1mm) and 6-Pin WSON (3 x 3 x 0.8 mm) Packaging
- Fully Enabled for WEBENCH® Power Designer

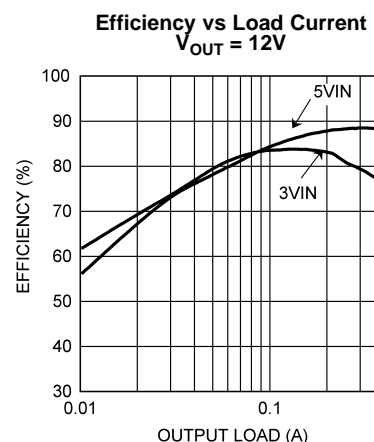
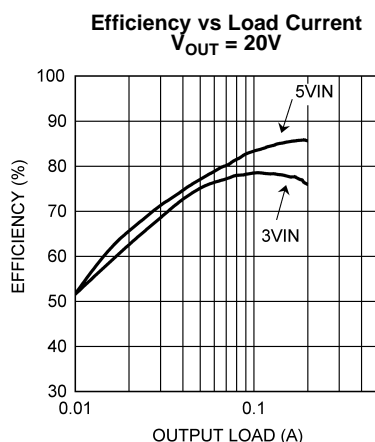
## PERFORMANCE BENEFITS

- Extremely Easy to Use
- Tiny Overall Solution Reduces System Cost

## APPLICATIONS

- Boost / SEPIC Conversions from 3.3V, 5V Rails
- Space Constrained Applications
- Embedded Systems
- LCD Displays
- LED Applications

## System Performance



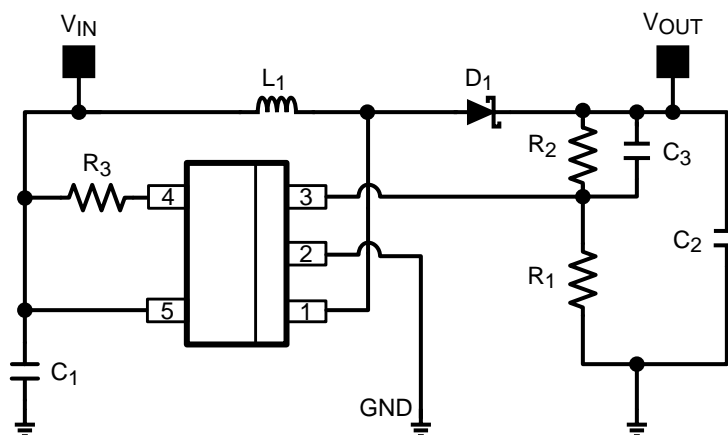
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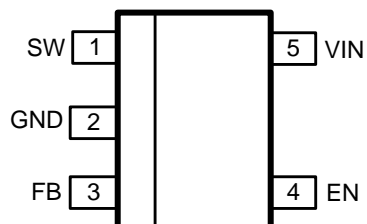
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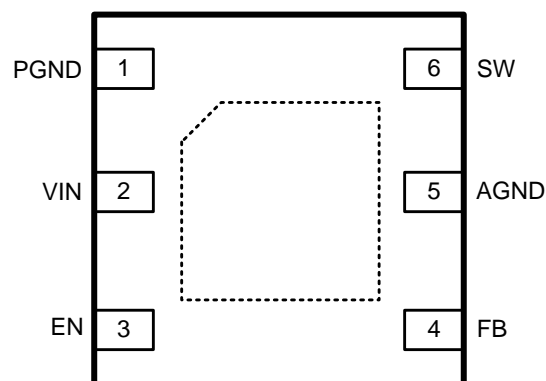
## Typical Application



## Connection Diagrams



**Figure 1. 5-Pin SOT-23 (Top View)**  
See DBV Package



**Figure 2. 6-Pin WSON (Top View)**  
See NGG0006A Package

### PIN DESCRIPTIONS - 5-Pin SOT-23

Pin	Name	Function
1	SW	Switch node. Connect to the inductor, output diode.
2	GND	Signal and power ground pin. Place the bottom resistor of the feedback network as close as possible to this pin.
3	FB	Feedback pin. Connect FB to external resistor divider to set output voltage.
4	EN	Shutdown control input. Logic high enables operation. Do not allow this pin to float or be greater than VIN + 0.3V.
5	VIN	Supply voltage for power stage, and input supply voltage.

### PIN DESCRIPTIONS - 6-Pin WSON

Pin	Name	Function
1	PGND	Power ground pin. Place PGND and output capacitor GND close together.
2	VIN	Supply voltage for power stage, and input supply voltage.
3	EN	Shutdown control input. Logic high enables operation. Do not allow this pin to float or be greater than VIN + 0.3V.
4	FB	Feedback pin. Connect FB to external resistor divider to set output voltage.
5	AGND	Signal ground pin. Place the bottom resistor of the feedback network as close as possible to this pin & pin 4.
6	SW	Switch node. Connect to the inductor, output diode.
DAP	GND	Signal & Power ground. Connect to pin 1 & pin 5 on top layer. Place 4-6 vias from DAP to bottom layer GND plane.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings<sup>(1)(2)</sup>

$V_{IN}$	-0.5V to 7V
SW Voltage	-0.5V to 26.5V
FB Voltage	-0.5V to 3.0V
EN Voltage	-0.5V to $V_{IN} + 0.3V$
ESD Susceptibility <sup>(3)</sup>	2kV
Junction Temperature <sup>(4)</sup>	150°C
Storage Temp. Range	-65°C to 150°C
For soldering specifications: <a href="#">SNOA549</a>	

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For specified specifications and the test conditions, see Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin.
- (4) Thermal shutdown will occur if the junction temperature exceeds the maximum junction temperature of the device.

### Operating Ratings<sup>(1)</sup>

$V_{IN}$	2.7V to 5.5V
$V_{EN}$ <sup>(2)</sup>	0V to $V_{IN}$
Junction Temperature Range	-40°C to +125°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For specified specifications and the test conditions, see Electrical Characteristics.
- (2) Do not allow this pin to float or be greater than  $V_{IN} + 0.3V$ .

## Electrical Characteristics<sup>(1)(2)</sup>

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in **boldface type** apply over the junction temperature range of ( $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$ ). Minimum and Maximum limits are ensured through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only.  $V_{IN} = 5\text{V}$  unless otherwise indicated under the Conditions column.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$V_{FB}$	Feedback Voltage	$-40^\circ\text{C} \leq T_J \leq +125^\circ\text{C}$ (SOT-23)	<b>1.230</b>	1.255	<b>1.280</b>	V
		$0^\circ\text{C} \leq T_J \leq +125^\circ\text{C}$ (SOT-23)	<b>1.236</b>	1.255	<b>1.274</b>	
		$-40^\circ\text{C} \leq T_J \leq +125^\circ\text{C}$ (WSON)	<b>1.225</b>	1.255	<b>1.285</b>	
		$-0^\circ\text{C} \leq T_J \leq +125^\circ\text{C}$ (WSON)	<b>1.229</b>	1.255	<b>1.281</b>	
$\Delta V_{FB}/V_{IN}$	Feedback Voltage Line Regulation	$V_{IN} = 2.7\text{V}$ to $5.5\text{V}$		0.06		%/V
$I_{FB}$	Feedback Input Bias Current			0.1	<b>1</b>	$\mu\text{A}$
$F_{SW}$	Switching Frequency		<b>1200</b>	1600	<b>2000</b>	kHz
$D_{MAX}$	Maximum Duty Cycle		<b>88</b>	96		%
$D_{MIN}$	Minimum Duty Cycle			5		%
$R_{DS(ON)}$	Switch On Resistance	SOT-23		170	<b>330</b>	m $\Omega$
		WSON		190	<b>350</b>	
$I_{CL}$	Switch Current Limit		<b>2.1</b>	3		A
SS	Soft Start			4		ms
$I_Q$	Quiescent Current (switching)			7.0	<b>11</b>	mA
	Quiescent Current (shutdown)	$V_{EN} = 0\text{V}$		80		nA
UVLO	Undervoltage Lockout	VIN Rising		2.3	<b>2.65</b>	V
		VIN Falling	<b>1.7</b>	1.9		
$V_{EN\_TH}$	Shutdown Threshold Voltage	See <sup>(3)</sup>			<b>0.4</b>	V
	Enable Threshold Voltage	See <sup>(3)</sup>	<b>1.8</b>			
$I_{SW}$	Switch Leakage	$V_{SW} = 24\text{V}$		1.0		$\mu\text{A}$
$I_{EN}$	Enable Pin Current	Sink/Source		100		nA
$\theta_{JA}$	Junction to Ambient 0 LFPM Air Flow <sup>(4)</sup>	WSON		80		$^\circ\text{C}/\text{W}$
		SOT-23		118		
$\theta_{JC}$	Junction to Case	WSON		18		$^\circ\text{C}/\text{W}$
		SOT-23		60		
$T_{SD}$	Thermal Shutdown Temperature <sup>(5)</sup>			160		$^\circ\text{C}$
	Thermal Shutdown Hysteresis			10		

- (1) Min and Max limits are 100% production tested at  $25^\circ\text{C}$ . Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).
- (2) Typical numbers are at  $25^\circ\text{C}$  and represent the most likely parametric norm.
- (3) Do not allow this pin to float or be greater than  $V_{IN} + 0.3\text{V}$ .
- (4) Applies for packages soldered directly onto a 3" x 3" PC board with 2oz. copper on 4 layers in still air.
- (5) Thermal shutdown will occur if the junction temperature exceeds the maximum junction temperature of the device.

## Typical Performance Characteristics

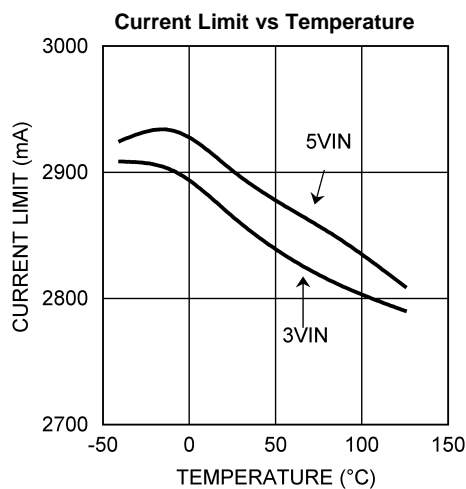


Figure 3.

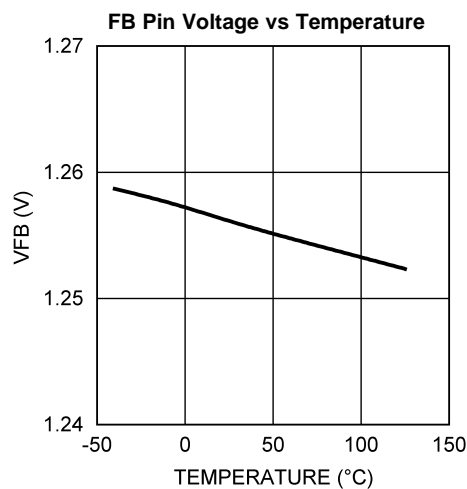


Figure 4.

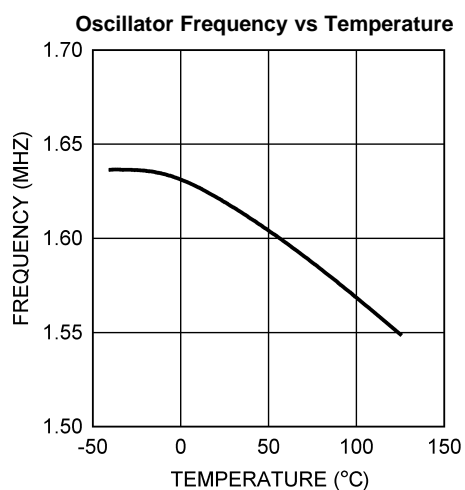


Figure 5.

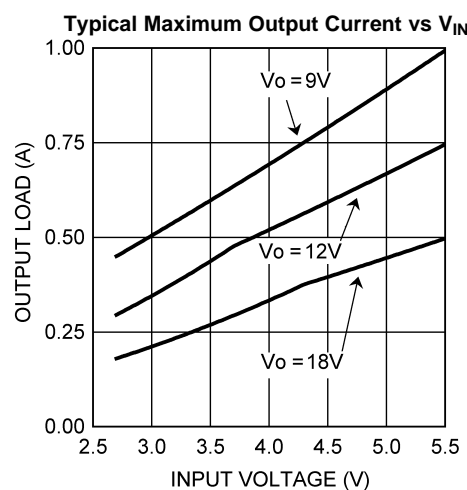


Figure 6.

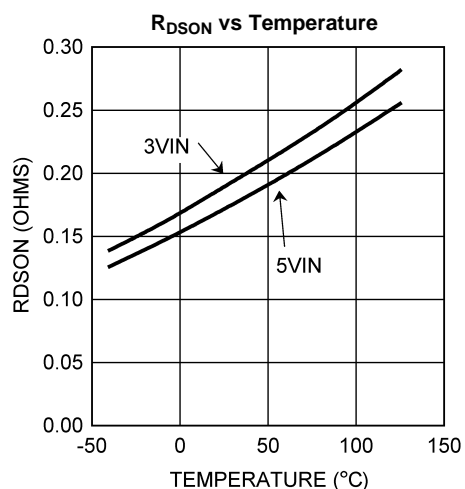


Figure 7.

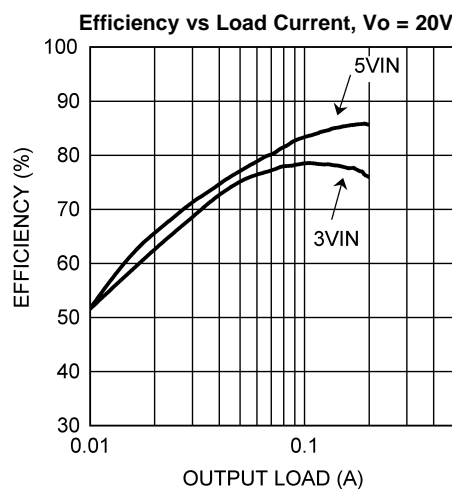


Figure 8.

## Typical Performance Characteristics (continued)

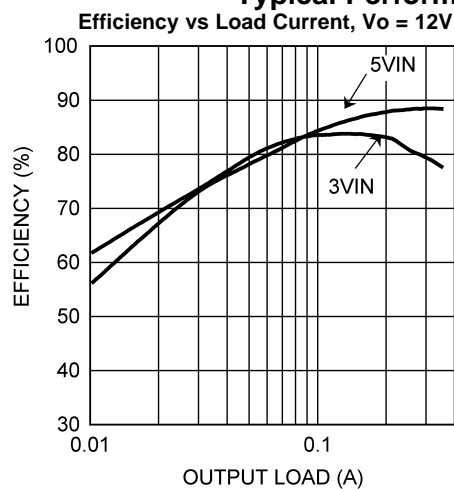


Figure 9.

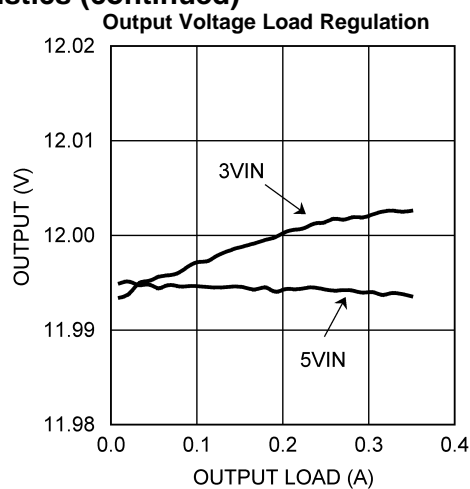


Figure 10.

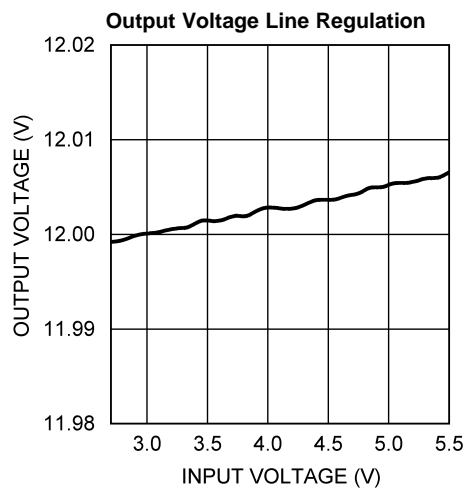


Figure 11.

## Simplified Internal Block Diagram

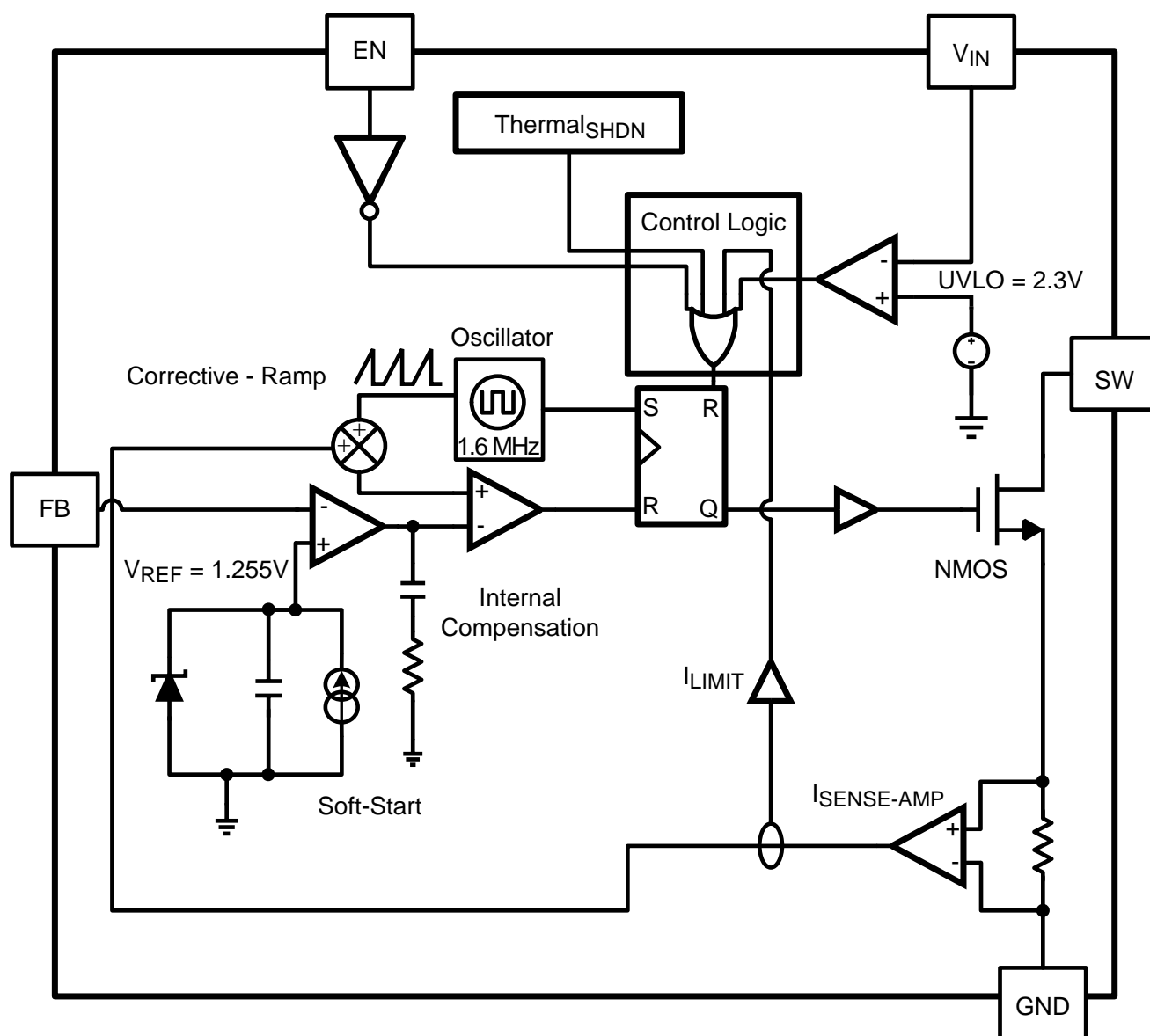


Figure 12. Simplified Block Diagram



## APPLICATION INFORMATION

### THEORY OF OPERATION

The following operating description of the LMR62421 will refer to the Simplified Block Diagram (Figure 12) the simplified schematic (Figure 13), and its associated waveforms (Figure 14). The LMR62421 supplies a regulated output voltage by switching the internal NMOS control switch at constant frequency and variable duty cycle. A switching cycle begins at the falling edge of the reset pulse generated by the internal oscillator. When this pulse goes low, the output control logic turns on the internal NMOS control switch. During this on-time, the SW pin voltage ( $V_{SW}$ ) decreases to approximately GND, and the inductor current ( $I_L$ ) increases with a linear slope.  $I_L$  is measured by the current sense amplifier, which generates an output proportional to the switch current. The sensed signal is summed with the regulator's corrective ramp and compared to the error amplifier's output, which is proportional to the difference between the feedback voltage and  $V_{REF}$ . When the PWM comparator output goes high, the output switch turns off until the next switching cycle begins. During the switch off-time, inductor current discharges through diode D1, which forces the SW pin to swing to the output voltage plus the forward voltage ( $V_D$ ) of the diode. The regulator loop adjusts the duty cycle (D) to maintain a constant output voltage.

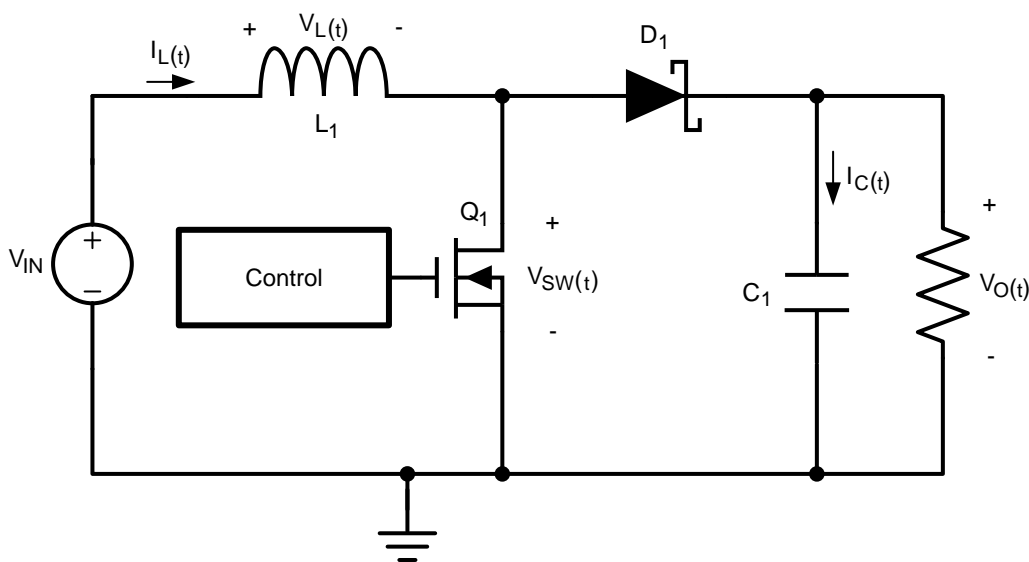


Figure 13. Simplified Schematic

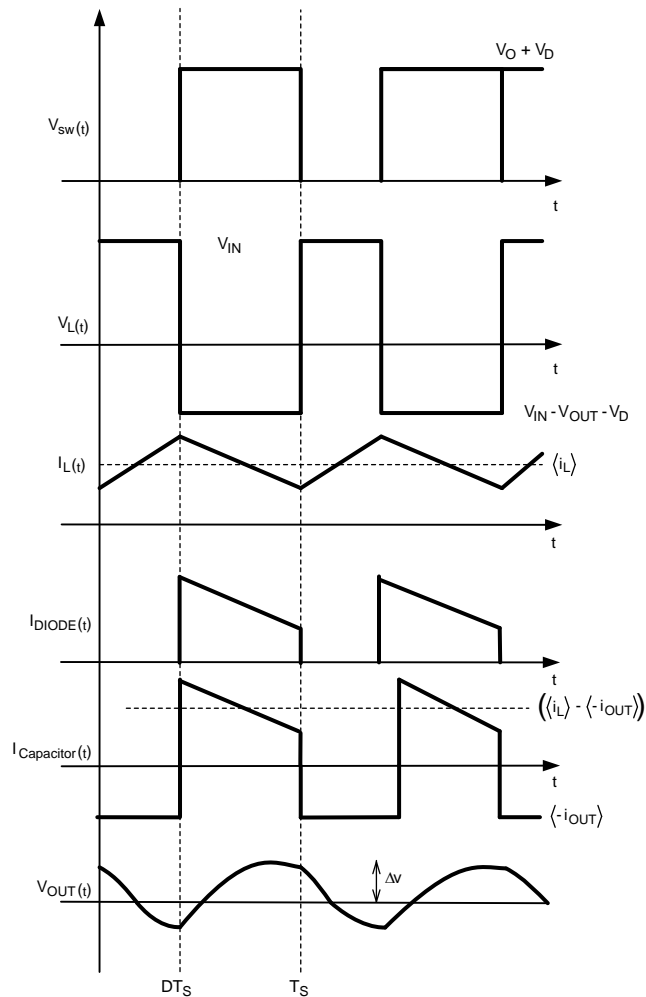


Figure 14. Typical Waveforms

## CURRENT LIMIT

The LMR62421 uses cycle-by-cycle current limiting to protect the internal NMOS switch. It is important to note that this current limit will not protect the output from excessive current during an output short circuit. The input supply is connected to the output by the series connection of an inductor and a diode. If a short circuit is placed on the output, excessive current can damage both the inductor and diode.

## Design Guide

### ENABLE PIN / SHUTDOWN MODE

The LMR62421 has a shutdown mode that is controlled by the Enable pin (EN). When a logic low voltage is applied to EN, the part is in shutdown mode and its quiescent current drops to typically 80 nA. Switch leakage adds up to another 1  $\mu$ A from the input supply. The voltage at this pin should never exceed  $V_{IN} + 0.3V$ .

### THERMAL SHUTDOWN

Thermal shutdown limits total power dissipation by turning off the output switch when the IC junction temperature exceeds 160°C. After thermal shutdown occurs, the output switch doesn't turn on until the junction temperature drops to approximately 150°C.

## SOFT-START

This function forces  $V_{OUT}$  to increase at a controlled rate during start up. During soft-start, the error amplifier's reference voltage ramps to its nominal value of 1.255V in approximately 4.0ms. This forces the regulator output to ramp up in a more linear and controlled fashion, which helps reduce inrush current.

## INDUCTOR SELECTION

The Duty Cycle (D) can be approximated quickly using the ratio of output voltage ( $V_O$ ) to input voltage ( $V_{IN}$ ):

$$\frac{V_{OUT}}{V_{IN}} = \left( \frac{1}{1-D} \right) = \frac{1}{D'} \quad (1)$$

Therefore:

$$D = \frac{V_{OUT} - V_{IN}}{V_{OUT}} \quad (2)$$

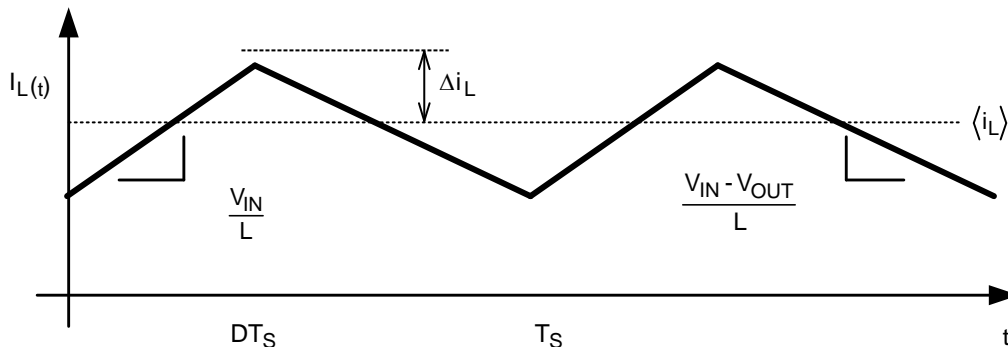
Power losses due to the diode (D1) forward voltage drop, the voltage drop across the internal NMOS switch, the voltage drop across the inductor resistance ( $R_{DCR}$ ) and switching losses must be included to calculate a more accurate duty cycle (See [Calculating Efficiency](#) and [Junction Temperature](#) for a detailed explanation). A more accurate formula for calculating the conversion ratio is:

$$\frac{V_{OUT}}{V_{IN}} = \frac{\eta}{D'}$$

where

- $\eta$  equals the efficiency of the LMR62421 application. (3)

The inductor value determines the input ripple current. Lower inductor values decrease the size of the inductor, but increase the input ripple current. An increase in the inductor value will decrease the input ripple current.



**Figure 15. Inductor Current**

$$\frac{2\Delta i_L}{DT_S} = \left( \frac{V_{IN}}{L} \right)$$

$$\Delta i_L = \left( \frac{V_{IN}}{2L} \right) \times DT_S \quad (4)$$

A good design practice is to design the inductor to produce 10% to 30% ripple of maximum load. From the previous equations, the inductor value is then obtained.

$$L = \left( \frac{V_{IN}}{2 \times \Delta i_L} \right) \times DT_S$$

where

- $1/T_S = F_{SW}$  = switching frequency (5)

One must also ensure that the minimum current limit (2.1A) is not exceeded, so the peak current in the inductor must be calculated. The peak current ( $I_{L_{PK}}$ ) in the inductor is calculated by:

$$I_{L_{PK}} = I_{IN} + \Delta i_L \quad (6)$$

or

$$I_{L_{PK}} = I_{OUT} / D' + \Delta i_L \quad (7)$$

When selecting an inductor, make sure that it is capable of supporting the peak input current without saturating. Inductor saturation will result in a sudden reduction in inductance and prevent the regulator from operating correctly. Because of the speed of the internal current limit, the peak current of the inductor need only be specified for the required maximum input current. For example, if the designed maximum input current is 1.5A and the peak current is 1.75A, then the inductor should be specified with a saturation current limit of >1.75A. There is no need to specify the saturation or peak current of the inductor at the 3A typical switch current limit.

Because of the operating frequency of the LMR62421, ferrite based inductors are preferred to minimize core losses. This presents little restriction since the variety of ferrite-based inductors is huge. Lastly, inductors with lower series resistance (DCR) will provide better operating efficiency. For recommended inductors see [Example Circuits](#).

## INPUT CAPACITOR

An input capacitor is necessary to ensure that  $V_{IN}$  does not drop excessively during switching transients. The primary specifications of the input capacitor are capacitance, voltage, RMS current rating, and ESL (Equivalent Series Inductance). The recommended input capacitance is 10  $\mu$ F to 44  $\mu$ F depending on the application. The capacitor manufacturer specifically states the input voltage rating. Make sure to check any recommended deratings and also verify if there is any significant change in capacitance at the operating input voltage and the operating temperature. The ESL of an input capacitor is usually determined by the effective cross sectional area of the current path. At the operating frequencies of the LMR62421, certain capacitors may have an ESL so large that the resulting impedance ( $2\pi fL$ ) will be higher than that required to provide stable operation. As a result, surface mount capacitors are strongly recommended. Multilayer ceramic capacitors (MLCC) are good choices for both input and output capacitors and have very low ESL. For MLCCs it is recommended to use X7R or X5R dielectrics. Consult capacitor manufacturer datasheet to see how rated capacitance varies over operating conditions.

## OUTPUT CAPACITOR

The LMR62421 operates at frequencies allowing the use of ceramic output capacitors without compromising transient response. Ceramic capacitors allow higher inductor ripple without significantly increasing output ripple. The output capacitor is selected based upon the desired output ripple and transient response. The initial current of a load transient is provided mainly by the output capacitor. The output impedance will therefore determine the maximum voltage perturbation. The output ripple of the converter is a function of the capacitor's reactance and its equivalent series resistance (ESR):

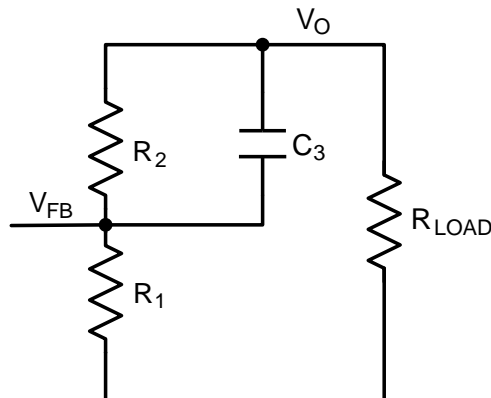
$$\Delta V_{OUT} = \Delta I_L \times R_{ESR} + \left( \frac{V_{OUT} \times D}{2 \times F_{SW} \times R_{Load} \times C_{OUT}} \right) \quad (8)$$

When using MLCCs, the ESR is typically so low that the capacitive ripple may dominate. When this occurs, the output ripple will be approximately sinusoidal and 90° phase shifted from the switching action .

Given the availability and quality of MLCCs and the expected output voltage of designs using the LMR62421, there is really no need to review any other capacitor technologies. Another benefit of ceramic capacitors is their ability to bypass high frequency noise. A certain amount of switching edge noise will couple through parasitic capacitances in the inductor to the output. A ceramic capacitor will bypass this noise while a tantalum will not. Since the output capacitor is one of the two external components that control the stability of the regulator control loop, most applications will require a minimum at 4.7 µF of output capacitance. Like the input capacitor, recommended multilayer ceramic capacitors are X7R or X5R. Again, verify actual capacitance at the desired operating voltage and temperature.

## SETTING THE OUTPUT VOLTAGE

The output voltage is set using the following equation where R1 is connected between the FB pin and GND, and R2 is connected between V<sub>OUT</sub> and the FB pin.



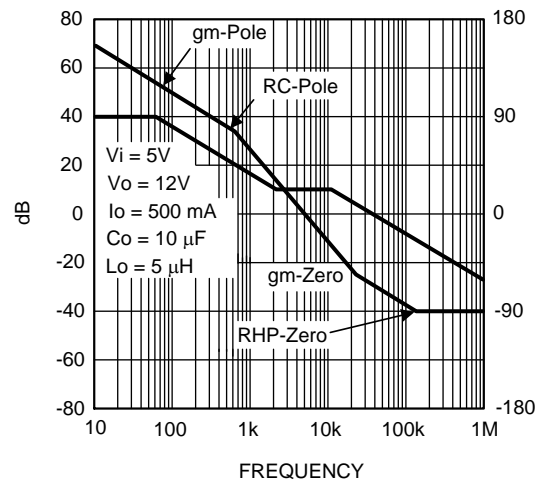
**Figure 16. Setting Vout**

A good value for R1 is 10kΩ.

$$R_2 = \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) \times R_1 \quad (9)$$

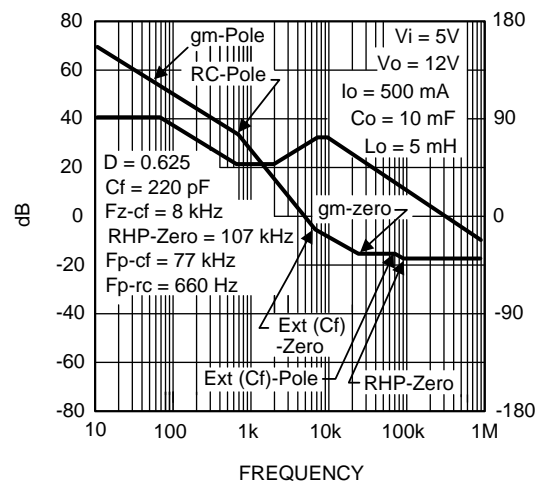
## COMPENSATION

The LMR62421 uses constant frequency peak current mode control. This mode of control allows for a simple external compensation scheme that can be optimized for each application. A complicated mathematical analysis can be completed to fully explain the LMR62421's internal & external compensation, but for simplicity, a graphical approach with simple equations will be used. Below is a Gain & Phase plot of a LMR62421 that produces a 12V output from a 5V input voltage. The Bode plot shows the total loop Gain & Phase without external compensation.



**Figure 17. LMR62421 Without External Compensation**

One can see that the Crossover frequency is fine, but the phase margin at 0dB is very low ( $22^\circ$ ). A zero can be placed just above the crossover frequency so that the phase margin will be bumped up to a minimum of  $45^\circ$ . Below is the same application with a zero added at 8 kHz.



**Figure 18. LMR62421 With External Compensation**

The simplest method to determine the compensation component value is as follows.

Set the output voltage with the following equation.

$$R_2 = \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) \times R_1$$

where

- R1 is the bottom resistor

and

- R2 is the resistor tied to the output voltage. (10)

The next step is to calculate the value of C3. The internal compensation has been designed so that when a zero is added between 5 kHz & 10 kHz the converter will have good transient response with plenty of phase margin for all input & output voltage combinations.

$$F_{ZERO-CF} = \frac{1}{2\pi(R_2 \times C_f)} = 5 \text{ kHz} \rightarrow 10 \text{ kHz} \quad (11)$$

Lower output voltages will have the zero set closer to 10 kHz, and higher output voltages will usually have the zero set closer to 5 kHz. It is always recommended to obtain a Gain/Phase plot for your actual application. One could refer to the [Typical Application](#) section to obtain examples of working applications and the associated component values.

Pole @ origin due to internal gm amplifier:

$$F_{P-ORIGIN} \quad (12)$$

Pole due to output load and capacitor:

$$F_{P-RC} = \frac{1}{2\pi(R_{LOAD}C_{OUT})} \quad (13)$$

This equation only determines the frequency of the pole for perfect current mode control (CMC). Therefore, it doesn't take into account the additional internal artificial ramp that is added to the current signal for stability reasons. By adding artificial ramp, you begin to move away from CMC to voltage mode control (VMC). The artifact is that the pole due to the output load and output capacitor will actually be slightly higher in frequency than calculated. In this example it is calculated at 650 Hz, but in reality it is around 1 kHz.

The zero created with capacitor C3 & resistor R2:

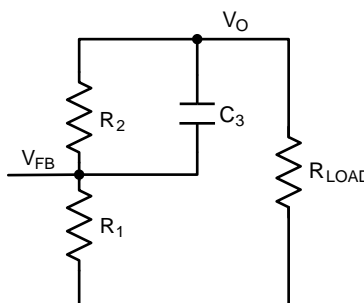


Figure 19. Setting External Pole-Zero

$$F_{\text{ZERO-CF}} = \frac{1}{2\pi(R_2 \times C_3)} \quad (14)$$

There is an associated pole with the zero that was created in the above equation.

$$F_{\text{POLE-CF}} = \frac{1}{2\pi((R_1 \parallel R_2) \times C_3)} \quad (15)$$

It is always higher in frequency than the zero.

A right-half plane zero (RHPZ) is inherent to all boost converters. One must remember that the gain associated with a right-half plane zero increases at 20dB per decade, but the phase decreases by 45° per decade. For most applications there is little concern with the RHPZ due to the fact that the frequency at which it shows up is well beyond crossover, and has little to no effect on loop stability. One must be concerned with this condition for large inductor values and high output currents.

$$\text{RHP}_{\text{ZERO}} = \frac{(D)^2 R_{\text{Load}}}{2\pi \times L} \quad (16)$$

There are miscellaneous poles and zeros associated with parasitics internal to the LMR62421, external components, and the PCB. They are located well over the crossover frequency, and for simplicity are not discussed.

## PCB Layout Considerations

When planning layout there are a few things to consider when trying to achieve a clean, regulated output. The most important consideration when completing a Boost Converter layout is the close coupling of the GND connections of the  $C_{\text{OUT}}$  capacitor and the LMR62421 PGND pin. The GND ends should be close to one another and be connected to the GND plane with at least two through-holes. There should be a continuous ground plane on the bottom layer of a two-layer board. The FB pin is a high impedance node and care should be taken to make the FB trace short to avoid noise pickup and inaccurate regulation. The feedback resistors should be placed as close as possible to the IC, with the AGND of R1 placed as close as possible to the GND (pin 5 for the WSON) of the IC. The  $V_{\text{OUT}}$  trace to R2 should be routed away from the inductor and any other traces that are switching. High AC currents flow through the  $V_{\text{IN}}$ , SW and  $V_{\text{OUT}}$  traces, so they should be as short and wide as possible. However, making the traces wide increases radiated noise, so the designer must make this trade-off. Radiated noise can be decreased by choosing a shielded inductor. The remaining components should also be placed as close as possible to the IC. Please see Application Note AN-1229 [SNVA054](#) for further considerations and the LMR62421 demo board as an example of a good layout.

## SEPIC Converter

The LMR62421 can easily be converted into a SEPIC converter. A SEPIC converter has the ability to regulate an output voltage that is either larger or smaller in magnitude than the input voltage. Other converters have this ability as well (CUK and Buck-Boost), but usually create an output voltage that is opposite in polarity to the input voltage. This topology is a perfect fit for Lithium Ion battery applications where the input voltage for a single cell Li-Ion battery will vary between 3V & 4.5V and the output voltage is somewhere in between. Most of the analysis of the LMR62421 Boost Converter is applicable to the LMR62421 SEPIC Converter.

### SEPIC Design Guide:

SEPIC Conversion ratio without loss elements:

$$\frac{V_o}{V_{\text{IN}}} = \frac{D}{D'} \quad (17)$$

Therefore:

$$D = \frac{V_o}{V_o + V_{\text{IN}}} \quad (18)$$



### Small ripple approximation:

In a well-designed SEPIC converter, the output voltage, and input voltage ripple, the inductor ripple and is small in comparison to the DC magnitude. Therefore it is a safe approximation to assume a DC value for these components. The main objective of the Steady State Analysis is to determine the steady state duty-cycle, voltage and current stresses on all components, and proper values for all components.

In a steady-state converter, the net volt-seconds across an inductor after one cycle will equal zero. Also, the charge into a capacitor will equal the charge out of a capacitor in one cycle.

Therefore:

$$I_{L2} = \left( \frac{D}{D'} \right) \times I_{L1}$$

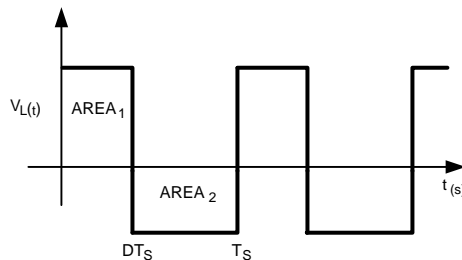
and

$$I_{L1} = \left( \frac{D}{D'} \right) \times \left( \frac{V_O}{R} \right) \quad (19)$$

Substituting  $I_{L1}$  into  $I_{L2}$

$$I_{L2} = \frac{V_O}{R} \quad (20)$$

The average inductor current of L2 is the average output load.



**Figure 20. Inductor Volt-Sec Balance Waveform**

Applying Charge balance on C1:

$$V_{C1} = \frac{D'(V_O)}{D} \quad (21)$$

Since there are no DC voltages across either inductor, and capacitor C6 is connected to  $V_{in}$  through L1 at one end, or to ground through L2 on the other end, we can say that

$$V_{C1} = V_{IN} \quad (22)$$

Therefore:

$$V_{IN} = \frac{D'(V_O)}{D} \quad (23)$$

This verifies the original conversion ratio equation.

It is important to remember that the internal switch current is equal to  $I_{L1}$  and  $I_{L2}$ . During the D interval. Design the converter so that the minimum ensured peak switch current limit (2.1A) is not exceeded.

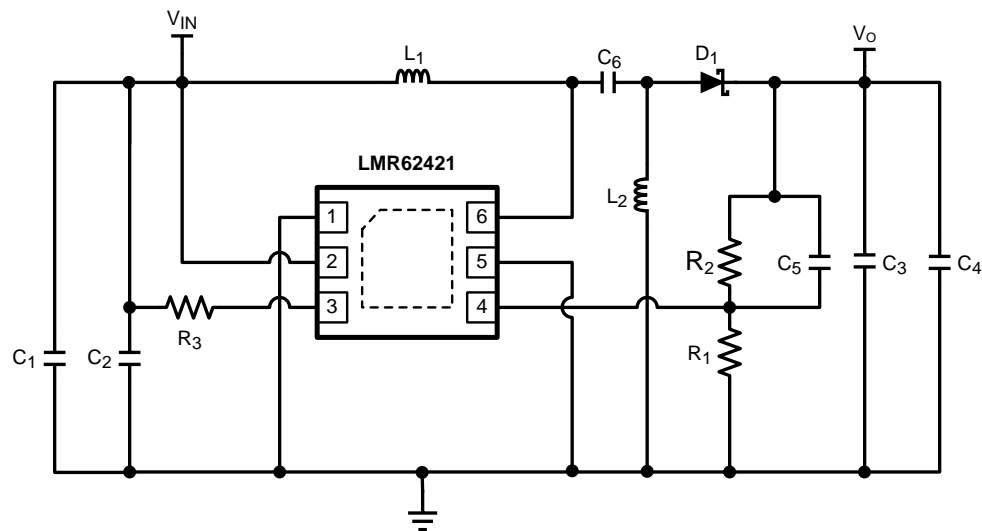
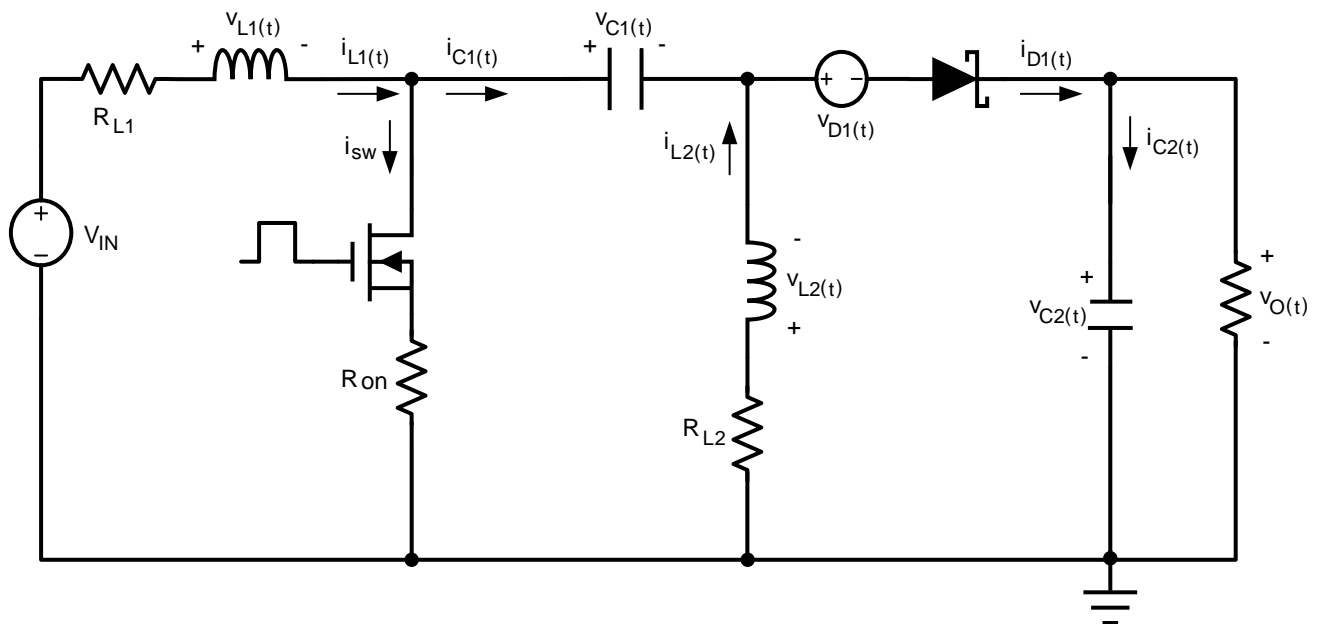


Figure 21. SEPIC CONVERTER Schematic

### Steady State Analysis with Loss Elements



Using inductor volt-second balance & capacitor charge balance, the following equations are derived:

$$I_{L2} = \left( \frac{V_O}{R} \right)$$

and

$$I_{L1} = \left( \frac{V_O}{R} \right) \times \left( \frac{D}{D'} \right) \quad (24)$$

$$\frac{V_O}{V_{IN}} = \left( \frac{D}{D'} \right) \left( \frac{1}{1 + \frac{V_D}{V_O} + \frac{R_{L2}}{R} + \left( \frac{D}{D'^2} \right) \left( \frac{R_{ON}}{R} \right) + \left( \frac{D^2}{D'^2} \right) \left( \frac{R_{L1}}{R} \right)} \right) \quad (25)$$

Therefore:

$$\eta = \left( \frac{1}{1 + \frac{V_D}{V_O} + \frac{R_{L2}}{R} + \left( \frac{D}{D'^2} \right) \left( \frac{R_{ON}}{R} \right) + \left( \frac{D^2}{D'^2} \right) \left( \frac{R_{L1}}{R} \right)} \right) \quad (26)$$

One can see that all variables are known except for the duty cycle (D). A quadratic equation is needed to solve for D. A less accurate method of determining the duty cycle is to assume efficiency, and calculate the duty cycle.

$$\frac{V_O}{V_{IN}} = \left( \frac{D}{1 - D} \right) \times \eta \quad (27)$$

$$D = \left( \frac{V_O}{(V_{IN} \times \eta) + V_O} \right) \quad (28)$$

**Table 1. Efficiencies for Typical SEPIC Application**

V <sub>in</sub>	2.7V	V <sub>in</sub>	3.3V	V <sub>in</sub>	5V
V <sub>o</sub>	3.1V	V <sub>o</sub>	3.1V	V <sub>o</sub>	3.1V
I <sub>in</sub>	770 mA	I <sub>in</sub>	600mA	I <sub>in</sub>	375 mA
I <sub>o</sub>	500 mA	I <sub>o</sub>	500mA	I <sub>o</sub>	500 mA
η	75%	η	80%	η	83%

## SEPIC Converter PCB Layout

The layout guidelines described for the LMR62421 Boost-Converter are applicable to the SEPIC Converter. Below is a proper PCB layout for a SEPIC Converter.

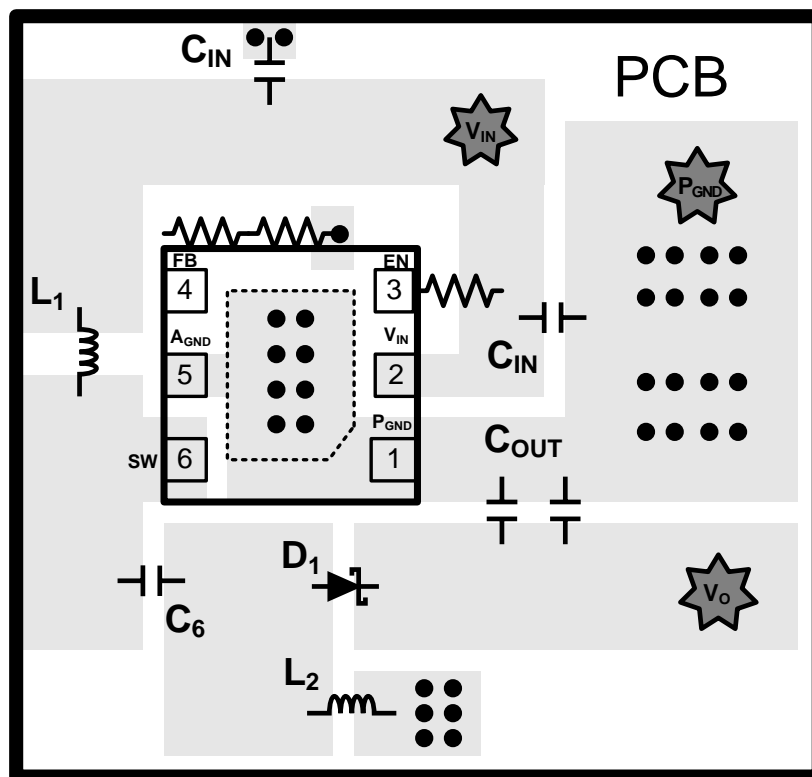


Figure 22. SEPIC PCB Layout

## WSO Package

The LMR62421 packaged in the 6-pin WSON:

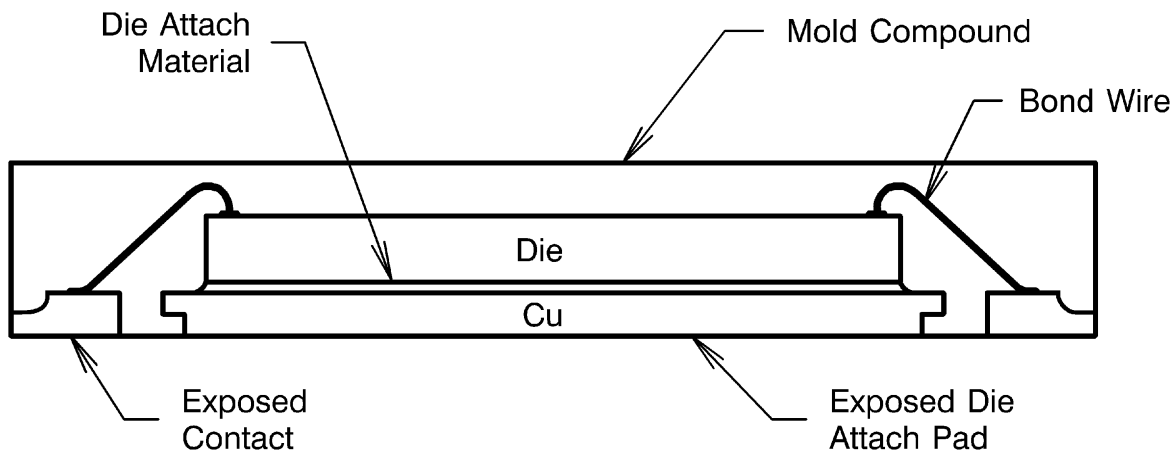


Figure 23. Internal WSON Connection

For certain high power applications, the PCB land may be modified to a "dog bone" shape (see Figure 24). Increasing the size of ground plane, and adding thermal vias can reduce the  $R_{\theta JA}$  for the application.

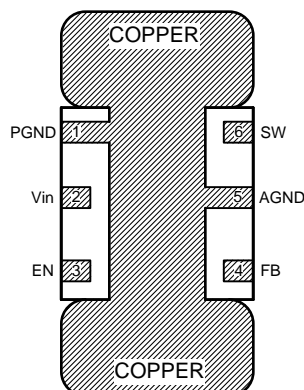


Figure 24. PCB Dog Bone Layout

### LMR62421 Design Example 1

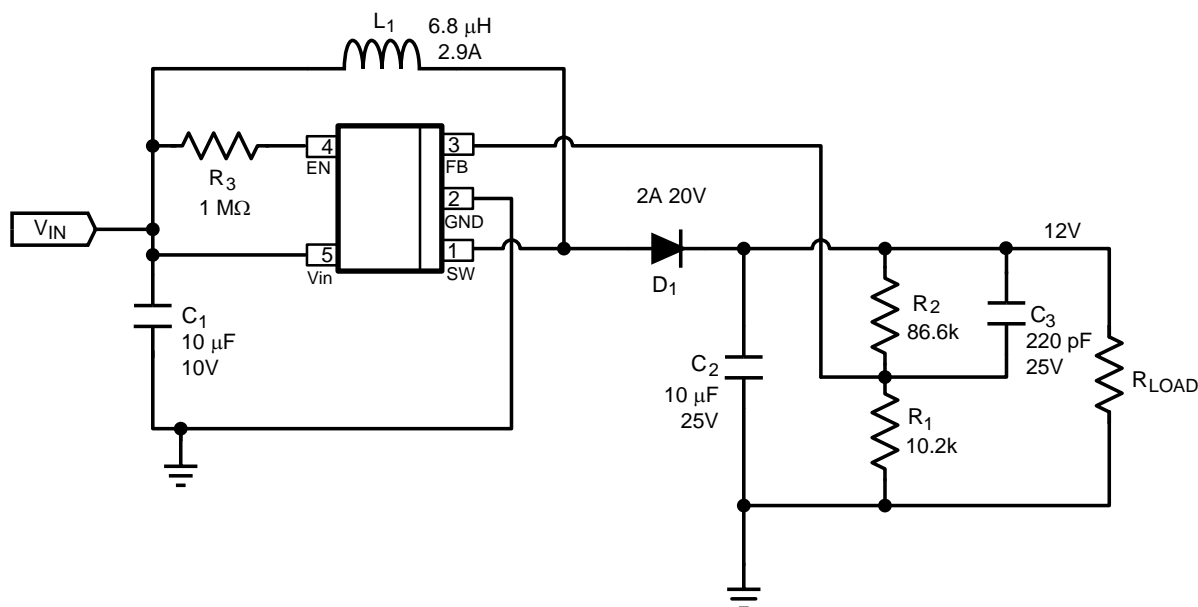


Figure 25.  $V_{in} = 3V - 5V$ ,  $V_{out} = 12V @ 500 mA$

## LMR62421 Design Example 2

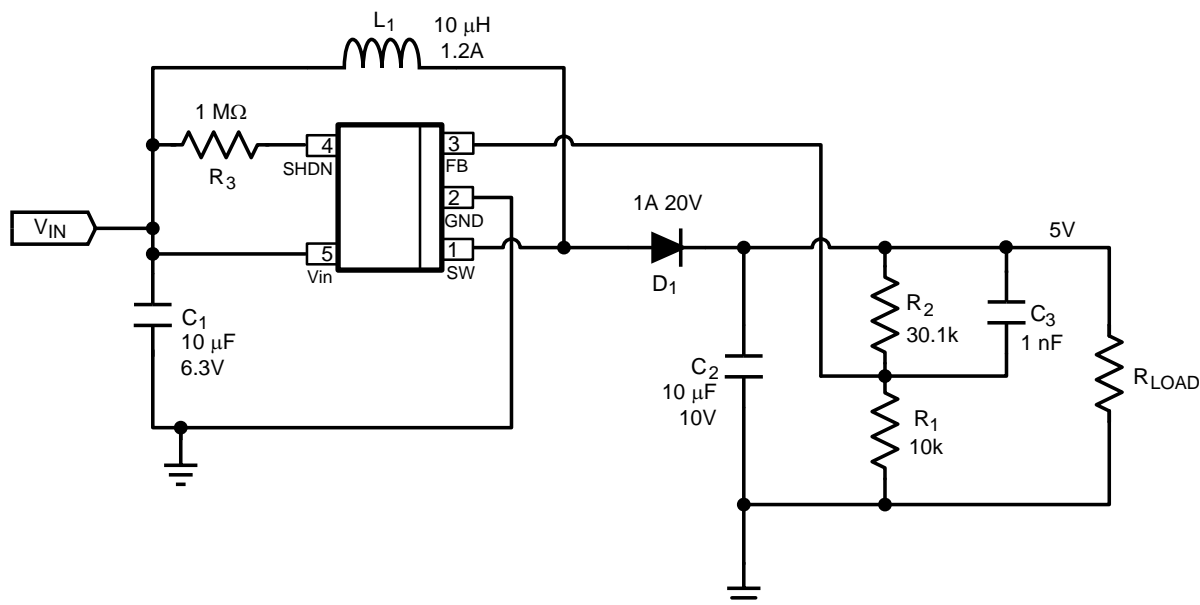


Figure 26.  $V_{in} = 3V$ ,  $V_{out} = 5V @ 500\text{ mA}$

## LMR62421 Design Example 3

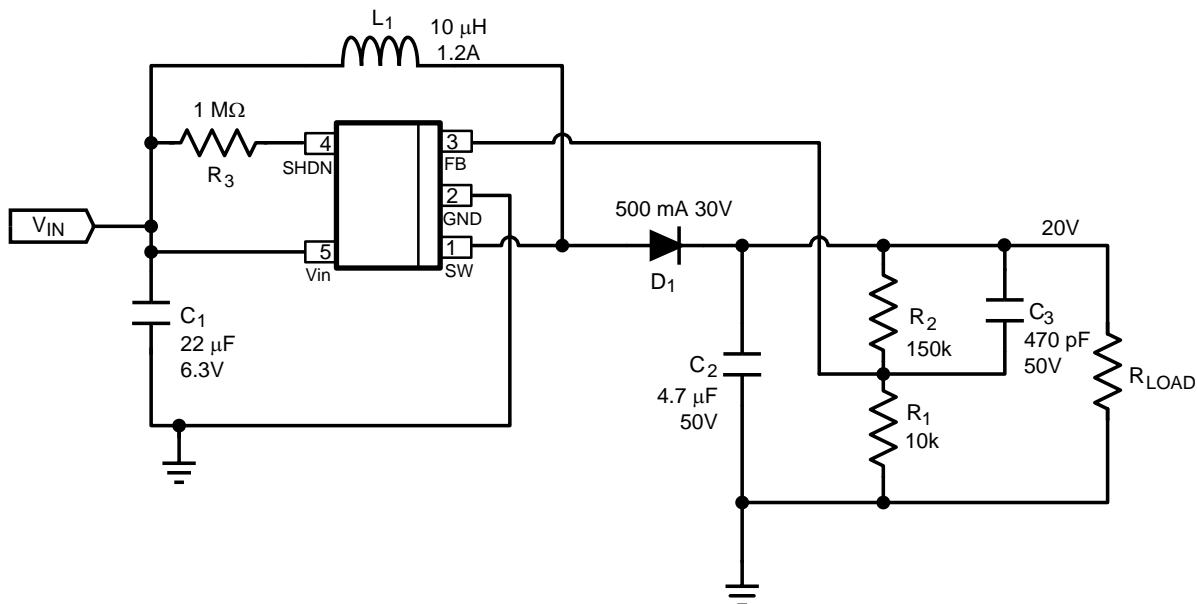


Figure 27.  $V_{in} = 3.3V$ ,  $V_{out} = 20V @ 100\text{ mA}$

# LMR62421 SEPIC Design Example 4

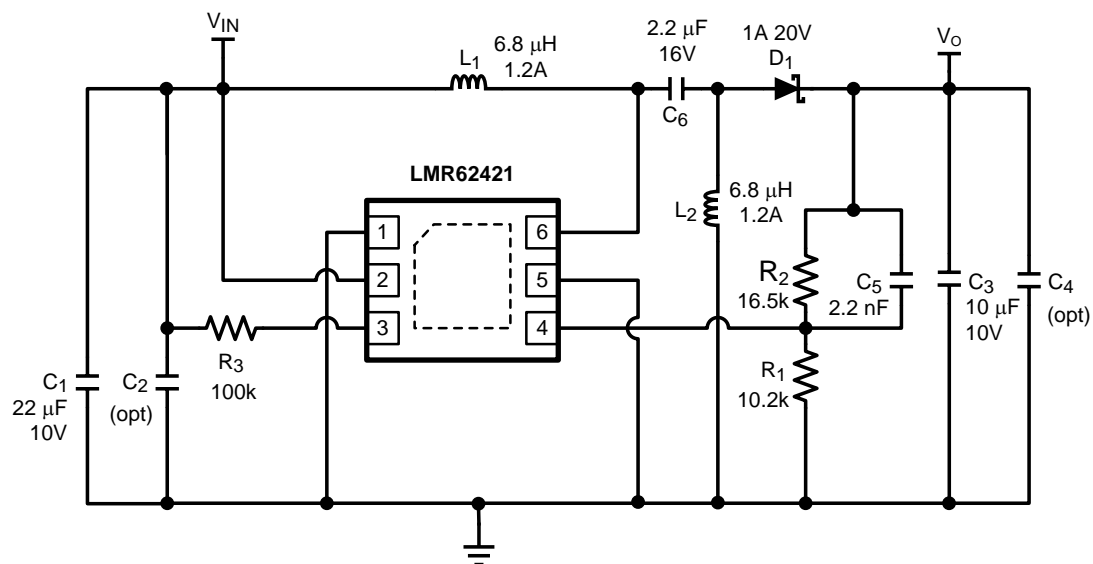


Figure 28.  $V_{in} = 2.7V - 5V$ ,  $V_{out} = 3.3V @ 500mA$

## REVISION HISTORY

### Changes from Revision A (April 2013) to Revision B

### Page

- Changed layout of National Data Sheet to TI format ..... [23](#)



## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMR62421XMF/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	SH8B	<a href="#">Samples</a>
LMR62421XMFE/NOPB	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	SH8B	<a href="#">Samples</a>
LMR62421XMF/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	SH8B	<a href="#">Samples</a>
LMR62421XSD/NOPB	ACTIVE	WSN	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L270B	<a href="#">Samples</a>
LMR62421XSDE/NOPB	ACTIVE	WSN	NGG	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L270B	<a href="#">Samples</a>
LMR62421XSDX/NOPB	ACTIVE	WSN	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L270B	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMR62421XMF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMR62421XMFE/NOPB	SOT-23	DBV	5	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMR62421XMF/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMR62421XSD/NOPB	WSO	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LMR62421XSDE/NOPB	WSO	NGG	6	250	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LMR62421XSDX/NOPB	WSO	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMR62421XMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMR62421XMFE/NOPB	SOT-23	DBV	5	250	210.0	185.0	35.0
LMR62421XMF/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMR62421XSD/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LMR62421XSDE/NOPB	WSON	NGG	6	250	210.0	185.0	35.0
LMR62421XSDX/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0

## DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-178 Variation AA.

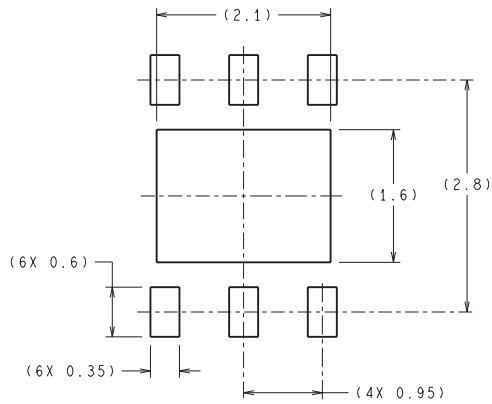
DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE

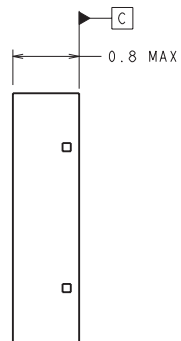
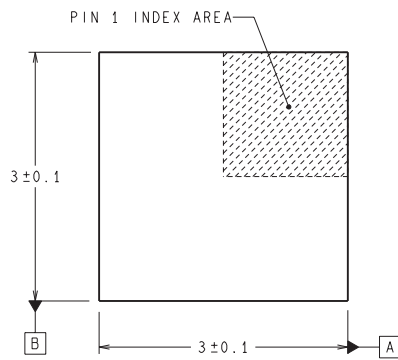


- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

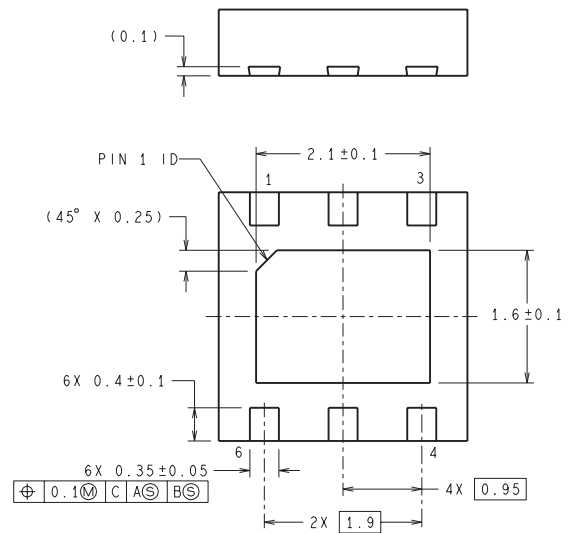
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